



### 20V P-Channel Enhancement Mode MOSFET - ESD Protected

Voltage -20 V Current -1.5A

#### **Features**

- RDS(ON), VGS@-4.5V, ID@-1.5A<325m $\Omega$
- R<sub>DS(ON)</sub> , V<sub>GS</sub>@-2.5V, I<sub>D</sub>@-1.2A<420mΩ</li>
- RDS(ON), VGS@-1.8V, ID@-0.5A<600m $\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in comply with EU RoHS 2011/65/EU directives.
- Green molding compound as per IEC61249 Std. (Halogen Free)

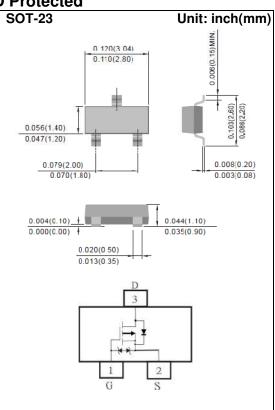
#### **Mechanical Data**

• Case: SOT-23 Package

Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A31



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 8	V
Continuous Drain Current		ID	-1.5	Α
Pulsed Drain Current (Note 4)		I <sub>DM</sub>	-4	Α
Power Dissipation	T <sub>a</sub> =25°C		1.25	W
	Derate above 25°C	P <sub>D</sub>	10	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	100	°C/W





### **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-0.5	-0.64	-1.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.5A	-	240	325	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1.2A	-	295	420	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-0.5A	-	405	600	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	-0.02	-1	uA
Gate-Source Leakage Current	Igss	V <sub>GS=+</sub> 8V, V <sub>DS</sub> =0V	-	<u>+</u> 3.5	<u>+</u> 10	uA
Dynamic			•			
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1.5A, V <sub>GS</sub> =-4.5V (Note 1,2)	-	1.7	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.35	-	
Gate-Drain Charge	$Q_{gd}$		-	0.43	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V,	-	165	-	pF
Output Capacitance	Coss		-	25	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	14.7	-	
Switching			•			
Turn-On Delay Time	td <sub>(on)</sub>		-	11	_	ns
Turn-On Rise Time	tr	$V_{DD}$ =-10V, $I_{D}$ =-1.5A, $V_{GS}$ =-4.5V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	38	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	130	-	
Turn-Off Fall Time	tf	HG=012 (Note 1,2)	-	75	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-1.6	А
Diode Forward Voltage	V <sub>SD</sub>	Is=-1.6A, V <sub>GS</sub> =0V	-	-1.03	-1.2	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch FR-4 with 2oz.square pad of copper.
- 4. The maximum current rating is package limited.





#### **TYPICAL CHARACTERISTIC CURVES**

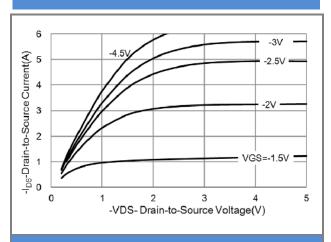


Fig.1 On-Region Characteristics

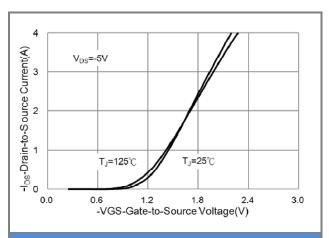


Fig.2 Transfer Characteristics

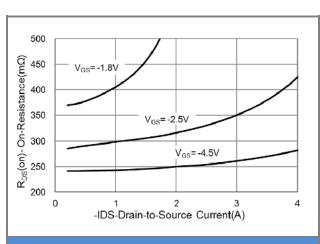


Fig.3 On-Resistance vs. Drain Current

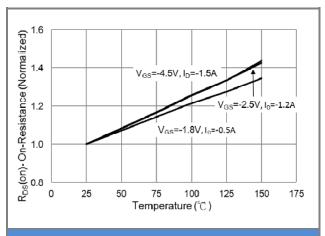
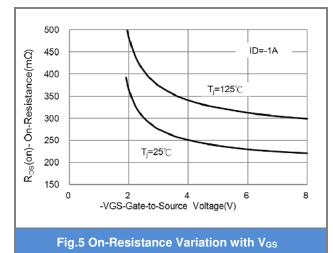
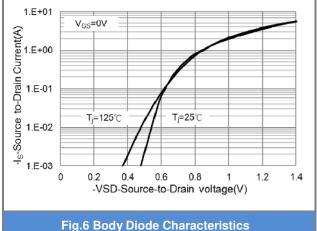


Fig.4 On-Resistance vs. Junction temperature









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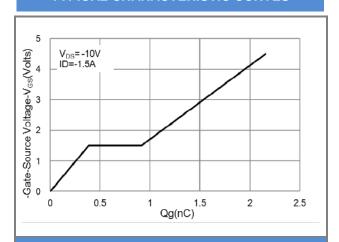


Fig.7 Gate-Charge Characteristics

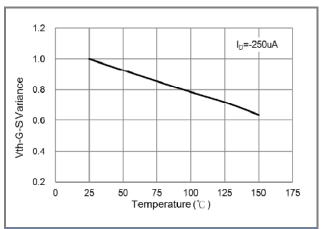


Fig.8 Threshold Voltage Variation with Temperature

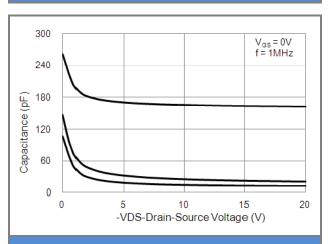


Fig.9 Capacitance vs. Drain-Source Voltage

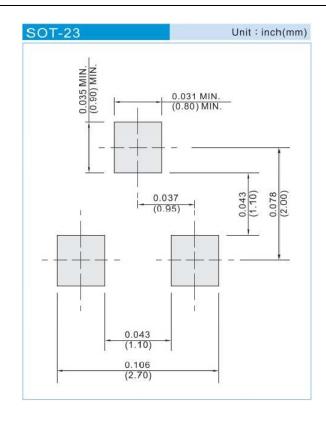




## Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJA3431_R1_00001	SOT-23	3K pcs / 7" reel	A31	Halogen free
PJA3431_R2_00001	SOT-23	12K pcs / 1" reel	A31	Halogen free

# **Mounting Pad Layout**







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